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# 1.8V Drive Nch+Nch MOSFET

# US6K4

#### Structure

Silicon N-channel MOSFET

#### ● Features

- 1) Two Nch MOSFETs are put in TUMT6 package.
- 2) High-speed switching, Low On-resistance.
- 3) 1.8V drive.

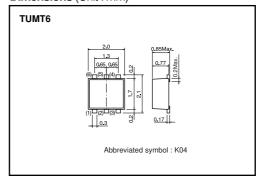
# Applications

Switching

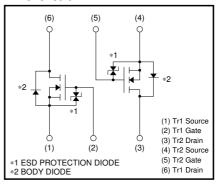
#### Packaging specifications

	Package	Taping
Type	Code	TR
	Basic ordering unit (pieces)	3000
US6K4		0

## ●Dimensions (Unit:mm)



#### Inner circuit



### ● **Absolute maximum ratings** (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2>

3					
Parameter		Symbol	Limits	Unit	
Drain-source voltage		VDSS	20	V	
Gate-source voltage		$V_{GSS}$	±10	V	
Drain current	Continuous	ID	±1.5	Α	
Drain current	Pulsed	I <sub>DP</sub> *1	±3.0	Α	
Source current	Continuous	ls	0.6	Α	
(Body diode)	Pulsed	Isp *1	2.4	Α	
Total power dissipation		Pp *2	1.0	W / TOTAL	
		ı D	0.7	W / ELEMENT	
Channel temperature		Tch	150	°C	
Range of storage temperature		Tsta	-55 to +150	°C	

<sup>\*1</sup> Pw≤10µs, Duty cycle≤1% \*2 Mounted on a ceramic board

#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	125	°C/W / TOTAL
Charmer to ambient		179	°C/W / ELEMENT

<sup>\*</sup> Mounted on a ceramic board

# ●Electrical characteristics (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2>

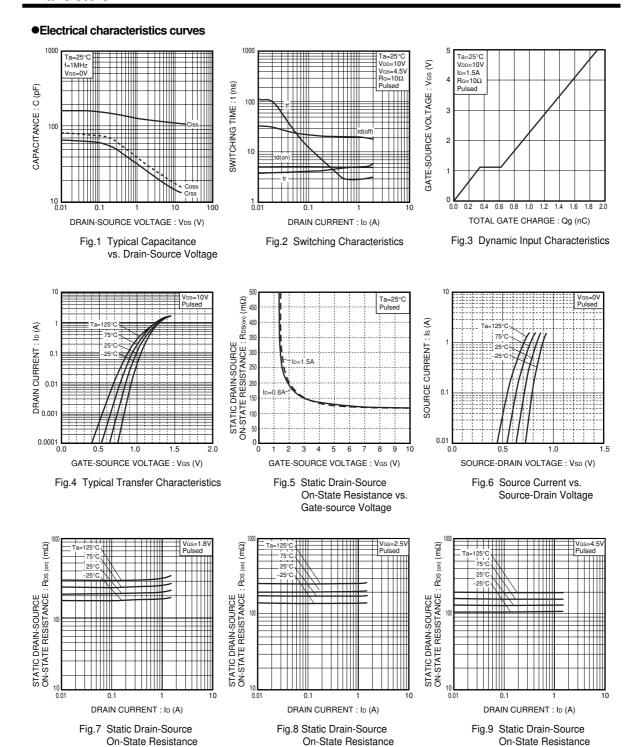
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μΑ	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	20	_	_	V	I <sub>D</sub> = 1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	IDSS	_	_	1	μΑ	V <sub>DS</sub> = 20V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	0.3	_	1.0	٧	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA
Static drain-source on-state resistance		_	130	180	mΩ	ID= 1.5A, VGS= 4.5V
	R <sub>DS (on)</sub> *	-	170	240	mΩ	I <sub>D</sub> = 1.5A, V <sub>GS</sub> = 2.5V
		_	220	310	mΩ	I <sub>D</sub> = 0.8A, V <sub>GS</sub> = 1.8V
Forward transfer admittance	Y <sub>fs</sub>   *	1.6	-	-	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1.5A
Input capacitance	Ciss	_	110	_	pF	V <sub>DS</sub> = 10V
Output capacitance	Coss	_	18	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	-	15	_	рF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub> *	_	5	_	ns	ID= 1.0A
Rise time	tr *	_	5	_	ns	V <sub>DD</sub> = 10V V <sub>GS</sub> = 4.5V R <sub>I</sub> = 10Ω
Turn-off delay time	td (off) *	_	20	_	ns	
Fall time	t <sub>f</sub> *	_	3	_	ns	Rgs=10Ω
Total gate charge	Qg *	_	1.8	2.5	nC	V <sub>DD</sub> ≒10V
Gate-source charge	Qgs *	_	0.3	-	nC	V <sub>GS</sub> = 4.5V
Gate-drain charge	Q <sub>gd</sub> *	_	0.3	_	nC	ID= 1.5A

<sup>\*</sup>Pulsed

# ●Body diode characteristics (Source-drain) (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VsD	_	_	1.2	V	I <sub>S</sub> = 0.6A, V <sub>GS</sub> =0V



# ●Notice

vs. Drain Current (I)

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

vs. Drain Current (II)

vs. Drain Current ( III )

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# US6K4 - Web Page

**Distribution Inventory** 

Part Number	US6K4
Package	TUMT6
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes